

Maximum Ratings N-CHANNEL – Q2 (@T_A = +25°C, unless otherwise specified.)

Char	Symbol	Value	Unit		
Drain-Source Voltage	V _{DSS}	30	V		
Gate-Source Voltage	V _{GSS}	±20	V		
Continuous Drain Current (Note 6)	Steady State	T _A = +25°C T _A = +85°C	ID	8.5 7.1	A
Pulsed Drain Current (Note 7)			I _{DM}	26	A

Maximum Ratings P-CHANNEL – Q1 (@T_A = +25°C, unless otherwise specified.)

Char	Symbol	Value	Unit		
Drain-Source Voltage	V _{DSS}	-30	V		
Gate-Source Voltage	V _{GSS}	±20	V		
Continuous Drain Current (Note 6)	Steady State	T _A = +25°C T _A = +85°C	ID	-7.0 -4.5	А
Pulsed Drain Current (Note 7)			I _{DM}	-25	A

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 6)	PD	2.5	W
Thermal Resistance, Junction to Ambient (Note 6)	R _{θJA}	50	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	С°

Electrical Characteristics N-CHANNEL – Q2 (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)							
Drain-Source Breakdown Voltage	BV _{DSS}	30	—	—	V	V_{GS} = 0V, I _D = 250µA	
Zero Gate Voltage Drain Current T _J = +25°C	I _{DSS}	_	_	1.0	μA	V _{DS} = 30V, V _{GS} = 0V	
Gate-Source Leakage	IGSS	—	—	±100	nA	V_{GS} = ±20V, V_{DS} = 0V	
ON CHARACTERISTICS (Note 8)							
Gate Threshold Voltage	V _{GS(th)}	1	1.45	2.1	V	$V_{DS} = V_{GS}$, $I_C = 250 \mu A$	
Static Drain-Source On-Resistance	Proven	—	14	21	mΩ	V _{GS} = 10V, I _C = 7A	
	R _{DS (ON)}	—	18	32	11152	V_{GS} = 4.5V, I _C = 5.6A	
Forward Transfer Admittance	Y _{fs}	_	8.1	_	S	V _{DS} = 5V, I _C = 7A	
Diode Forward Voltage (Note 8)	V _{SD}	_	0.7	1.0	V	V _{GS} = 0V, I _S = 1A	
DYNAMIC CHARACTERISTICS (Note 9)							
Input Capacitance	Ciss	—	767	—	pF		
Output Capacitance	Coss	—	110	—	pF	−V _{DS} = 10V, V _{GS} = 0V, −f = 1MHz	
Reverse Transfer Capacitance	C _{rss}		105	—	pF		
Gate Resistance	Rg	—	1.4	_	Ω	V_{DS} = 0V, V_{GS} = 0V, f = 1MHz	
Total Gate Charge (V _{GS} = 4.5V)	Qg	—	7.8	_	nC		
Total Gate Charge (V _{GS} = 10V)	Qg	—	16.1	_	nC		
Gate-Source Charge	Q _{gs}	—	1.8	—	nC	– V _{DS} = 15V, I _D = 9A	
Gate-Drain Charge	Q _{gd}	—	2.5		nC	7	
Turn-On Delay Time	t _{D(on)}	—	5.0	_	ns		
Turn-On Rise Time	tr		4.5		ns	V _{GS} = 10V, V _{DS} = 15V,	
Turn-Off Delay Time	t _{D(off)}		26.3		ns	R _G = 6Ω , I _D = 1A	
Turn-Off Fall Time	t _f	—	8.55	_	ns		

6. Device mounted on FR-4 PCB, with minimum recommended pad layout.

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Notes:

= 25°Ċ

T_A = 150°Ċ T_A = 125°C

T_A = 85°C

T_A = 25°C

T_A = -55°C

25

30

20

V_{GS} = 10V

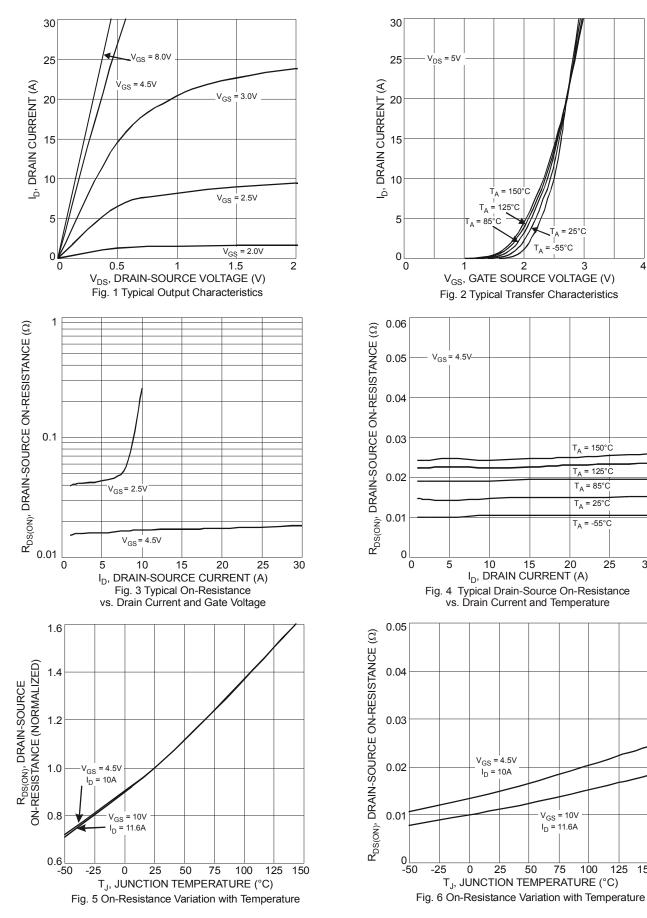
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100

125

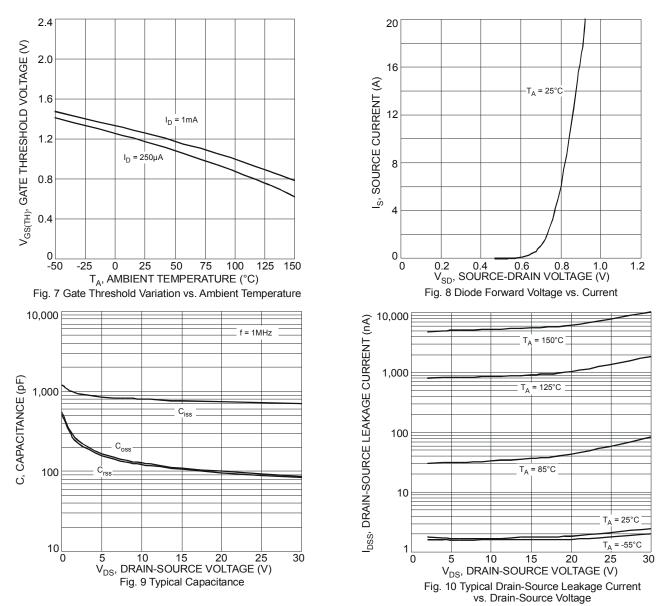
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150





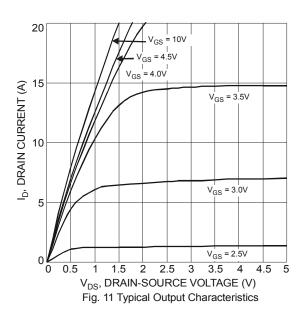


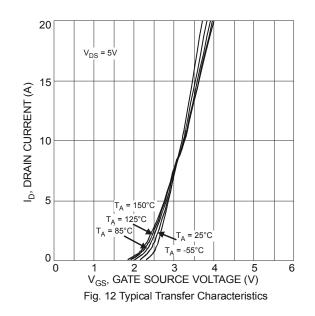
Electrical Characteristics P-CHANNEL – Q1 (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)							
Drain-Source Breakdown Voltage	BV _{DSS}	-30	—	—	V	$V_{GS} = 0V, I_D = -250 \mu A$	
Zero Gate Voltage Drain Current T _J = +25°C	I _{DSS}		—	-1.0	μA	V_{DS} = -30V, V_{GS} = 0V	
Gate-Source Leakage	I _{GSS}		—	±100	nA	V_{GS} = ±20V, V_{DS} = 0V	
ON CHARACTERISTICS (Note 8)							
Gate Threshold Voltage	V _{GS(th)}	-1	-1.7	-2.2	V	$V_{DS} = V_{GS}$, $I_D = -250 \mu A$	
Static Drain-Source On-Resistance	Proven		30	39	mΩ	V_{GS} = -10V, I_{D} = -4.3A	
	R _{DS(ON)}	_	42	53		V _{GS} = -4.5V, I _D = -3.7A	
Forward Transfer Admittance	Y _{fs}	_	7	—	S	V _{DS} = -5V, I _D = -4.3A	
Diode Forward Voltage (Note 8)	V _{SD}	_	-0.75	-1.0	V	V _{GS} = 0V, I _S = -1.7A	
DYNAMIC CHARACTERISTICS (Note 9)	•						
Input Capacitance	C _{iss}	_	1002	—	pF		
Output Capacitance	Coss	_	125	—	pF	V _{DS} = -10V, V _{GS} = 0V, f = 1.0MHz	
Reverse Transfer Capacitance	C _{rss}	_	118	—	pF		
Gate Resistance	Rg	_	13	—	Ω	V_{DS} = 0V, V_{GS} = 0V, f = 1MHz	
Total Gate Charge (V _{GS} = 4.5V)	Qg	_	10.1	—	nC		
Total Gate Charge (V _{GS} = 10V)	Qg		21.1	—	nC	V _{DS} = -15V, I _D = -6A	
Gate-Source Charge	Q _{gs}		2.8	—	nC		
Gate-Drain Charge	Q _{gd}	_	3.2	—	nC		
Turn-On Delay Time	t _{D(on)}		10.1	—	ns		
Turn-On Rise Time	tr	_	6.5	—	ns	V _{GS} = -10V, V _{DS} = -15V,	
Turn-Off Delay Time	t _{D(off)}	_	50.1	—	ns	$R_G = 6\Omega$, $I_D = -1A$	
Turn-Off Fall Time	t _f	—	22.2	—	ns	1	

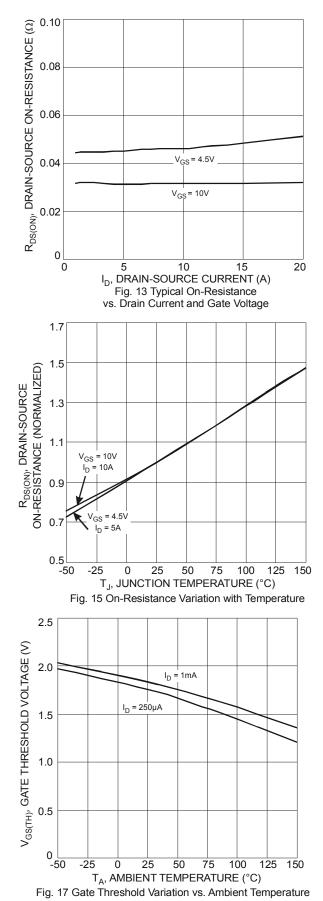
Notes: 8. Short duration pulse test used to minimize self-heating effect.

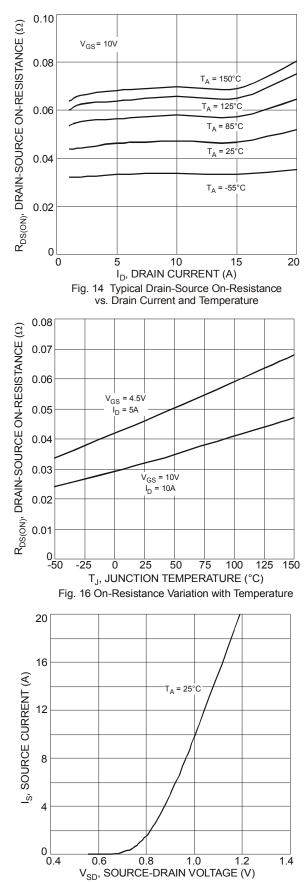
9. Guaranteed by design. Not subject to production testing.





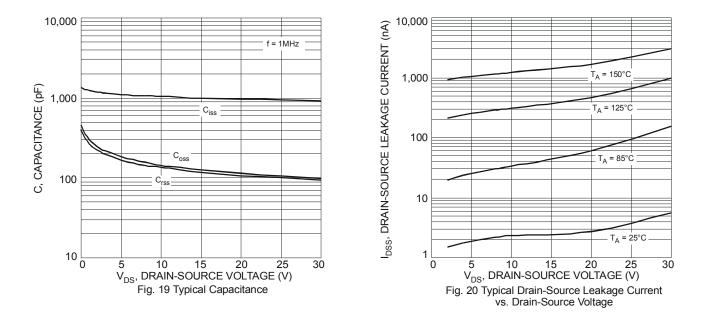






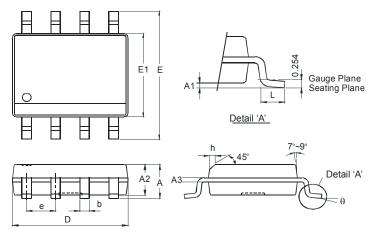
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Package Outline Dimensions

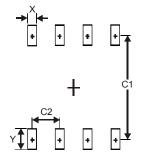
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



SO-8						
Dim	Min	Max				
Α	-	1.75				
A1	0.10	0.20				
A2	1.30	1.50				
A3	0.15	0.25				
b	0.3	0.5				
D	4.85	4.95				
Е	5.90	6.10				
E1	3.85	3.95				
е	е 1.27 Тур					
h	- 0.35					
L	0.62	0.82				
θ	0° 8°					
All Dimensions in mm						

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for latest version.



Dimensions	Value (in mm)
Х	0.60
Y	1.55
C1	5.4
C2	1.27



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